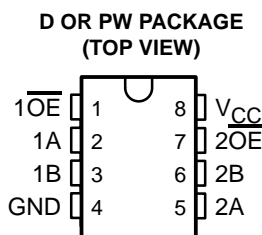


2.5-V/3.3-V LOW-VOLTAGE, HIGH-BANDWIDTH FET BUS SWITCH

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- Low and Flat On-State Resistance ( $r_{on}$ ) Characteristics Over Operating Range ( $r_{on} = 4 \Omega$  Typical)
- 0- to 5-V Rail-to-Rail Switching on Data I/O Ports
- $V_{CC}$  Operating Range From 2.3 V to 3.6 V
- TTL- and LVTTL-Compatible Data I/O Ports
- LVTTL-Compatible Control Inputs
- Bidirectional Data Flow With Near-Zero Propagation Delay
- Low Input/Output Capacitance Minimizes Loading and Signal Distortion ( $C_{iO} = 3.5$  pF Typical)
- Fast Switching Speeds ( $f_{OE} = 20$  MHz Max)
- High-Bandwidth Data Path (Up To 533 MHz)
- Low Power Consumption ( $I_{CC} = 250 \mu A$  Typical)
- $I_{off}$  on A and B Port for Partial-Power-Down Operation
- Data and Control Inputs Provide Undershoot Clamp Diodes
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 1000-V Charged-Device Model (C101)
- Supports Both Digital and Analog Applications: PCI Hot Plug, Hot Docking, Memory Interleaving, Bus Isolation, and Low-Distortion Signal Gating



description/ordering information

Texas Instruments bus switches provide high-performance, low-power replacements for standard bus-interface devices when signal buffering (current drive) is not required. The CB3Q family of high-bandwidth bus switches offers low and flat on-state resistance ( $r_{on}$ ), 0- to 5-V rail-to-rail switching on the data input/output (I/O) ports, and low data I/O capacitance ( $C_{iO}$ ) to minimize capacitive loading and signal distortion on the data bus. Specifically designed to support high-bandwidth applications, the CB3Q family provides an optimized interface solution ideally suited for broadband communications, networking, and data-intensive computing systems.

The SN74CB3Q3306 is a dual FET bus switch featuring independent line switches. Each switch is enabled when the associated output-enable ( $\overline{OE}$ ) input is low, allowing bidirectional data flow between ports A and B. Each switch is disabled when the associated  $\overline{OE}$  input is high, producing a high-impedance state between ports A and B. The very low  $r_{on}$  of the switch allows connections to be made with minimal propagation delay.

ORDERING INFORMATION

$T_A$	PACKAGE†		ORDERABLE PART NUMBER	TOP-SIDE MARKING
-40°C to 85°C	SOIC – D	Tube	SN74CB3Q3306D	BU306
		Tape and reel	SN74CB3Q3306DR	
	TSSOP – PW	Tape and reel	SN74CB3Q3306PWR	BU306

† Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at [www.ti.com/sc/package](http://www.ti.com/sc/package).



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PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



**SN74CB3Q3306**  
**DUAL SWITCH**  
**2.5-V/3.3-V LOW-VOLTAGE, HIGH-BANDWIDTH FET BUS SWITCH**

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**description/ordering information (continued)**

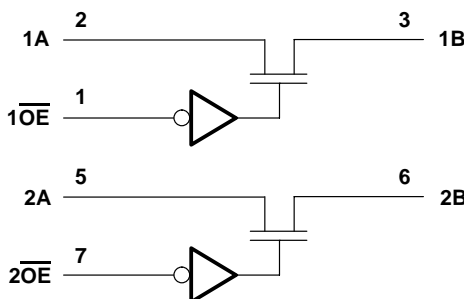
This device is fully specified for partial-power-down applications using  $I_{off}$ . The  $I_{off}$  circuitry prevents damaging current backflow through the device when it is powered down.

To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

**FUNCTION TABLE**  
(each bus switch)

INPUT $\overline{OE}$	FUNCTION
L	A port = B port
H	Disconnect

**logic diagram (positive logic)**



**absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†**

Supply voltage range, $V_{CC}$	–0.5 V to 4.6 V
Input voltage range, $V_I$ (see Note 1)	–0.5 V to 6.5 V
Continuous channel current	128 mA
Input clamp current, $I_{IK}$ ( $V_{I/O} < 0$ )	–50 mA
Package thermal impedance, $\theta_{JA}$ (see Note 2): D package	97°C/W
PW package	149°C/W
Storage temperature range, $T_{stg}$	–65°C to 150°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.  
 2. The package thermal impedance is calculated in accordance with JESD 51-7.

**recommended operating conditions (see Note 3)**

		MIN	MAX	UNIT
$V_{CC}$	Supply voltage	2.3	3.6	V
$V_{IH}$	High-level control input voltage	$V_{CC} = 2.3\text{ V to }2.7\text{ V}$	1.7	V
		$V_{CC} = 2.7\text{ V to }3.6\text{ V}$	2	
$V_{IL}$	Low-level control input voltage	$V_{CC} = 2.3\text{ V to }2.7\text{ V}$	0.7	V
		$V_{CC} = 2.7\text{ V to }3.6\text{ V}$	0.8	
$T_A$	Operating free-air temperature	–40	85	°C

NOTE 3: All unused control inputs of the device must be held at  $V_{CC}$  or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.



## 2.5-V/3.3-V LOW-VOLTAGE, HIGH-BANDWIDTH FET BUS SWITCH

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP†	MAX	UNIT
$V_{IK}$		$V_{CC} = 3.6\text{ V}$ ,	$I_I = -18\text{ mA}$			-1.8	V
$I_{IN}$	Control inputs	$V_{CC} = 3.6\text{ V}$ ,	$V_{IN} = 5.5\text{ V}$ or GND			$\pm 1$	$\mu\text{A}$
$I_{OZ}^\ddagger$		$V_{CC} = 3.6\text{ V}$ ,	$V_{I/O} = V_{CC}$ or GND			$\pm 1$	$\mu\text{A}$
$I_{off}$		$V_{CC} = 0$ ,	$V_{I/O} = 0$ to $5.5\text{ V}$			$\pm 1$	$\mu\text{A}$
$I_{CC}$		$V_{CC} = 3.6\text{ V}$ ,	$I_{I/O} = 0$ , $V_{IN} = V_{CC}$ or GND	250	700		$\mu\text{A}$
$\Delta I_{CC}^\S$	Control inputs	$V_{CC} = 3.6\text{ V}$ ,	One input at $3\text{ V}$ , Other inputs at $V_{CC}$ or GND			25	$\mu\text{A}$
$I_{CCD}^\parallel$		$V_{CC} = 3.6\text{ V}$ , A and B pins open, Per $\overline{OE}$ control input switching at 50% duty cycle			0.03	0.1	mA/ MHz
$C_{in}$	Control inputs	$V_{IN} = 5.5\text{ V}$ , $3.3\text{ V}$ , or $0$ ,	$V_{CC} = 3.3\text{ V}$		2.5	3.5	pF
$C_{iO(OFF)}$		$V_{I/O} = 5.5\text{ V}$ , $3.3\text{ V}$ , or $0$ ,	$V_{CC} = 3.3\text{ V}$ , Switch off, $\overline{OE} = V_{CC}$		3.5	5	pF
$C_{iO(ON)}$		$V_{I/O} = 5.5\text{ V}$ , $3.3\text{ V}$ , or $0$ ,	$V_{CC} = 3.3\text{ V}$ , Switch on, $\overline{OE} = \text{GND}$		8	10.5	pF
$r_{on}^\#$	$V_{CC} = 2.3\text{ V}$ , TYP at $V_{CC} = 2.5\text{ V}$	$V_I = 0$ ,	$I_O = 30\text{ mA}$		4	8	$\Omega$
		$V_I = 1.7\text{ V}$ ,	$I_O = -15\text{ mA}$		5	9	
	$V_{CC} = 3\text{ V}$	$V_I = 0$ ,	$I_O = 30\text{ mA}$		4	6	
		$V_I = 2.4\text{ V}$ ,	$I_O = -15\text{ mA}$		5	8	

$V_{IN}$  and  $I_{IN}$  refer to control inputs.  $V_I$ ,  $V_O$ ,  $I_I$ , and  $I_O$  refer to data pins.

† All typical values are at  $V_{CC} = 3.3\text{ V}$  (unless otherwise noted),  $T_A = 25^\circ\text{C}$ .

‡ For I/O ports, the parameter  $I_{OZ}$  includes the input leakage current.

§ This is the increase in supply current for each input that is at the specified TTL voltage level, rather than  $V_{CC}$  or GND.

¶ This parameter specifies the dynamic power-supply current associated with the operating frequency of a single  $\overline{OE}$  control input. The total  $I_{CC}$  can be calculated with the following formula: Total  $I_{CC} = I_{CC} + (I_{CCD} \times 1\overline{OE}\text{ frequency}) + (I_{CCD} \times 2\overline{OE}\text{ frequency})$ .

# Measured by the voltage drop between the A and B terminals at the indicated current through the switch. On-state resistance is determined by the lower of the voltages of the two (A or B) terminals.

switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	$V_{CC} = 2.5\text{ V} \pm 0.2\text{ V}$		$V_{CC} = 3.3\text{ V} \pm 0.3\text{ V}$		UNIT
			MIN	MAX	MIN	MAX	
$f_{\overline{OE}}^{\parallel}$	$\overline{OE}$	A or B		10		20	MHz
$t_{pd}^*$	A or B	B or A		0.2		0.2	ns
$t_{en}$	$\overline{OE}$	A or B	1.5	6.5	1.5	5.5	ns
$t_{dis}$	$\overline{OE}$	A or B	1	6	1	5	ns

¶ Maximum toggle frequency for  $\overline{OE}$  control input ( $V_O > V_{CC}$ ,  $V_I = 5\text{ V}$ ,  $R_L \geq 1\text{ M}\Omega$ ,  $C_L = 0$ )

\* The propagation delay is the calculated RC time constant of the typical on-state resistance of the switch and the specified load capacitance when driven by an ideal voltage source (zero output impedance).

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**DUAL SWITCH**  
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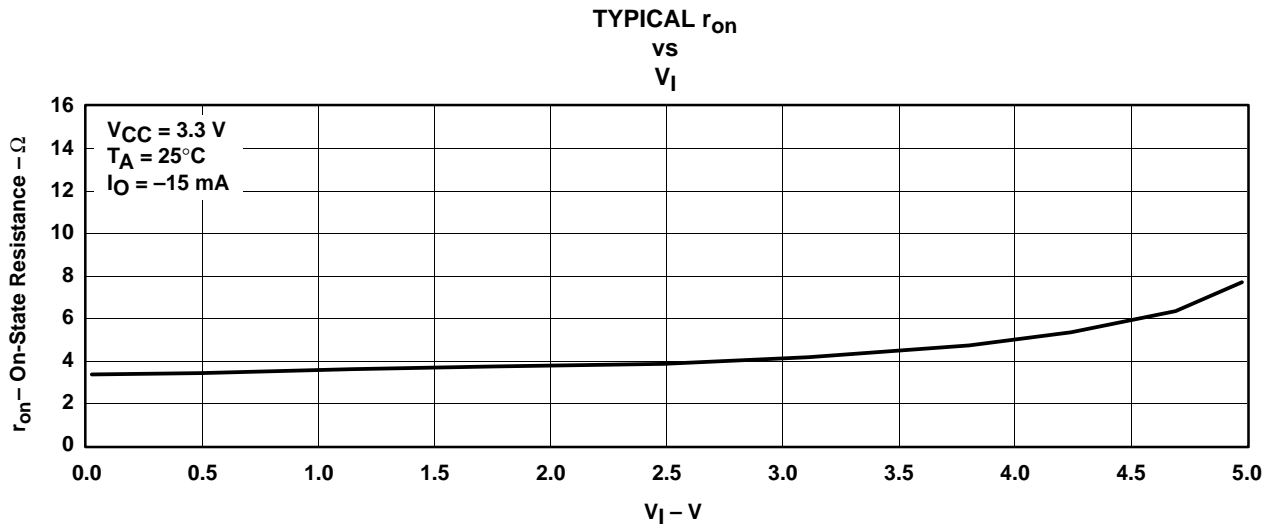


Figure 1. Typical  $r_{on}$  vs  $V_I$ ,  $V_{CC} = 3.3$  V and  $I_O = -15$  mA

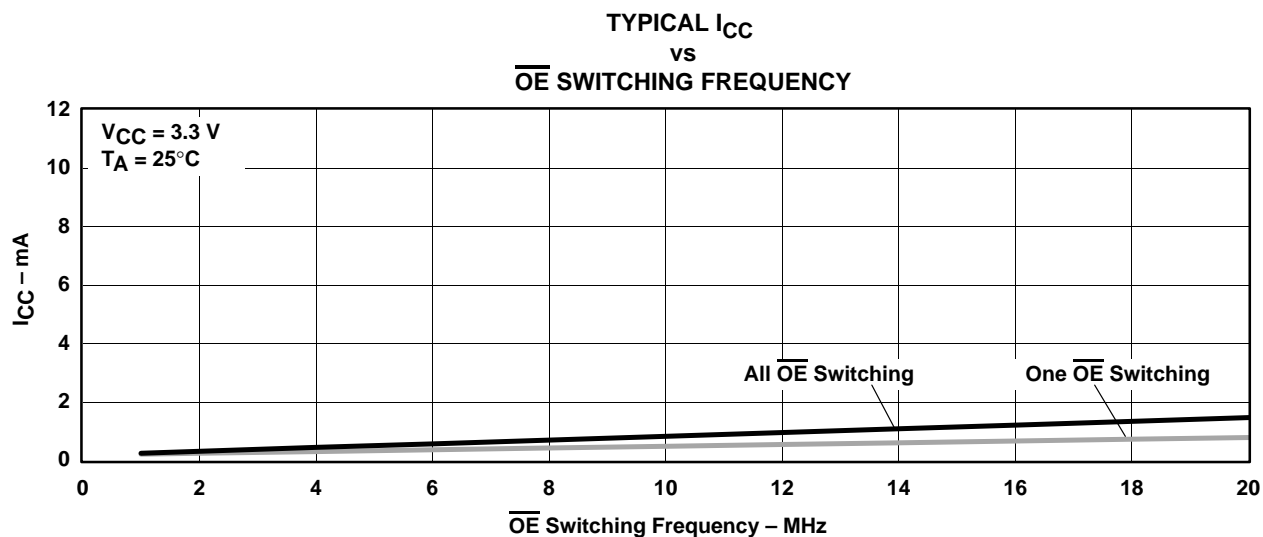
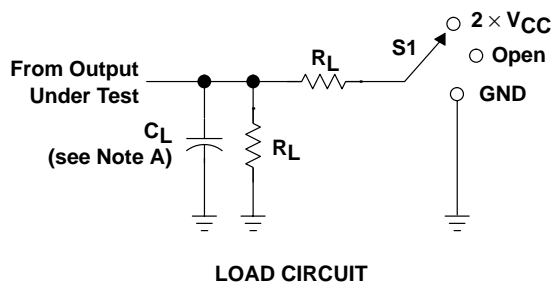


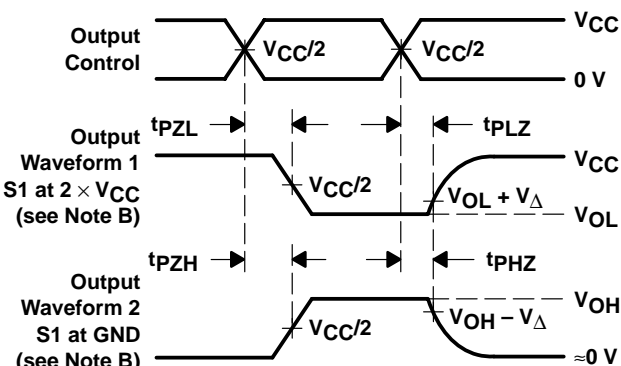
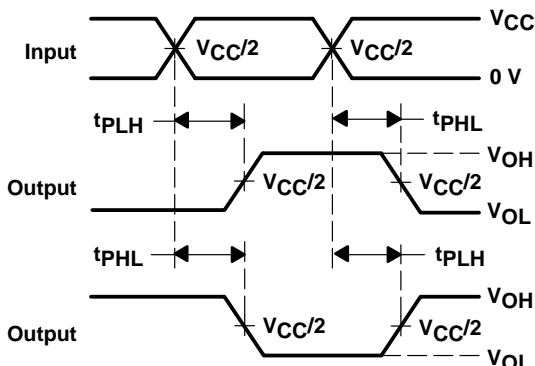
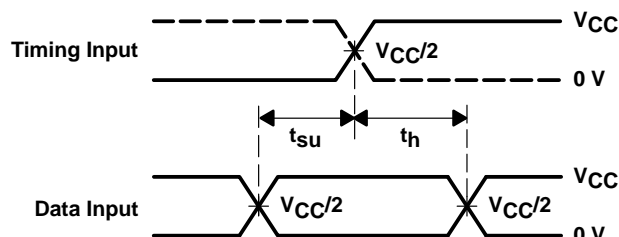
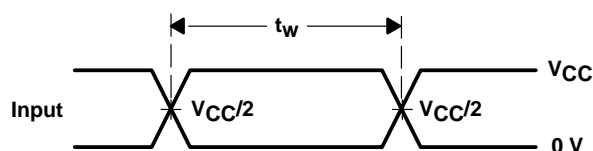
Figure 2. Typical  $I_{CC}$  vs  $\overline{OE}$  Switching Frequency,  $V_{CC} = 3.3$  V

PARAMETER MEASUREMENT INFORMATION



TEST	S1
$t_{PLH}/t_{PHL}$	Open
$t_{PLZ}/t_{PZL}$	$2 \times V_{CC}$
$t_{PHZ}/t_{PZH}$	GND

$V_{CC}$	$C_L$	$R_L$	$V_{\Delta}$
$2.5\text{ V} \pm 0.2\text{ V}$	30 pF	500 $\Omega$	0.15 V
$3.3\text{ V} \pm 0.3\text{ V}$	50 pF	500 $\Omega$	0.3 V



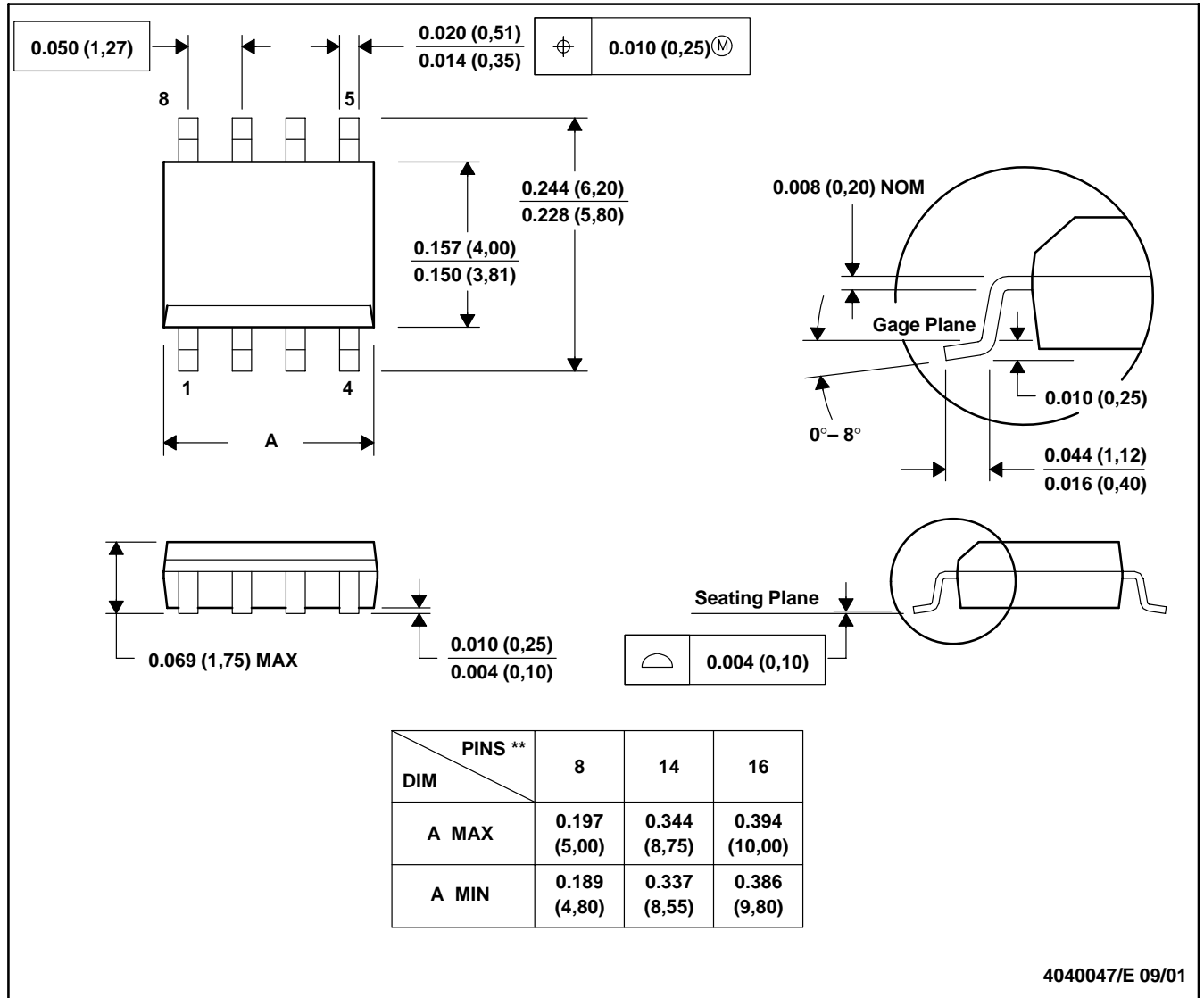
- NOTES: A.  $C_L$  includes probe and jig capacitance.  
 B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.  
 C. All input pulses are supplied by generators having the following characteristics:  $PRR \leq 10\text{ MHz}$ ,  $Z_O = 50\ \Omega$ ,  $t_r \leq 2\text{ ns}$ ,  $t_f \leq 2\text{ ns}$ .  
 D. The outputs are measured one at a time with one transition per measurement.  
 E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .  
 F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .  
 G.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .  
 H. All parameters and waveforms are not applicable to all devices.

Figure 3. Load Circuit and Voltage Waveforms

D (R-PDSO-G\*\*)

PLASTIC SMALL-OUTLINE PACKAGE

8 PINS SHOWN



- NOTES: A. All linear dimensions are in inches (millimeters).  
 B. This drawing is subject to change without notice.  
 C. Body dimensions do not include mold flash or protrusion, not to exceed 0.006 (0,15).  
 D. Falls within JEDEC MS-012

PW (R-PDSO-G\*\*)

PLASTIC SMALL-OUTLINE PACKAGE

14 PINS SHOWN



- NOTES: A. All linear dimensions are in millimeters.  
 B. This drawing is subject to change without notice.  
 C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.  
 D. Falls within JEDEC MO-153

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